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ON Semiconductor®

FAN54040 — FAN54047
USB-OTG, 1.55 A, Li-Ion Switching Charger with Power Path and 2.3 A Production Test Support

Features

- Fully Integrated, High-Efficiency Charger for Single-Cell Li-Ion and Li-Polymer Battery Packs
- Power Path Circuit Ensures Fast System Startup with a Dead Battery when VBUS is Connected
- 1.55 A Maximum Charge Current
- Float Voltage Accuracy:
  - ±0.5% at 25°C
  - ±1% from 0 to 125°C
- ±5% Input and Charge Current Regulation Accuracy
- Temperature-Sense Input Prevents Auto-Charging for JEITA Compliance
- Thermal Regulation and Shutdown
- 4.2 V at 2.3 A Production Test Mode
- 5 V, 500 mA Boost Mode for USB OTG
- 28 V Absolute Maximum Input Voltage
- 6 V Maximum Input Operating Voltage
- Programmable through High-Speed I^2C Interface (3.4 Mb/s) with Fast Mode Plus Compatibility
  - Input Current
  - Fast-Charge / Termination Current
  - Float Voltage
  - Termination Enable
- 3 MHz Synchronous Buck PWM Controller with Wide Duty Cycle Range
- Small Footprint 1 μH External Inductor
- Safety Timer with Reset Control
- Dynamic Input Voltage Control
- Very Low Battery Current when Charger Inactive

Applications

- Cell Phones, Smart Phones, PDAs
- Tablet, Portable Media Players
- Gaming Device, Digital Cameras

Description

The FAN5404X family includes I^2C controlled 1.55 A USB-compliant switch-mode chargers with power path operation and USB OTG boost operation. Integrated with the charger, the IC supports production test mode, which provides 4.2 V at up to 2.3 A to the system.

To facilitate fast system startup, the IC includes a power path circuit, which disconnects the battery from the system rail, ensuring that the system can power up quickly following a VBUS connection. The power path circuit ensures that the system rail stays up when the charger is plugged in, even if the battery is dead or shorted.

The charging parameters and operating modes are programmable through an I^2C Interface that operates up to 3.4 Mbps. The charger and boost regulator circuits switch at 3 MHz to minimize the size of external passive components.

The FAN5404X provides battery charging in three phases: conditioning, constant current, and constant voltage. The integrated circuit automatically restarts the charge cycle when the battery falls below a voltage threshold. If the input source is removed, the IC enters a high-impedance mode blocking battery current from leaking to the input. Charge status is reported back to the host through the I^2C port.

Dynamic input voltage control prevents a weak adapter's voltage from collapsing, ensuring charging capability from such adapters.

The FAN5404X is available in a 25-bump, 0.4 mm pitch, WLCSP package.

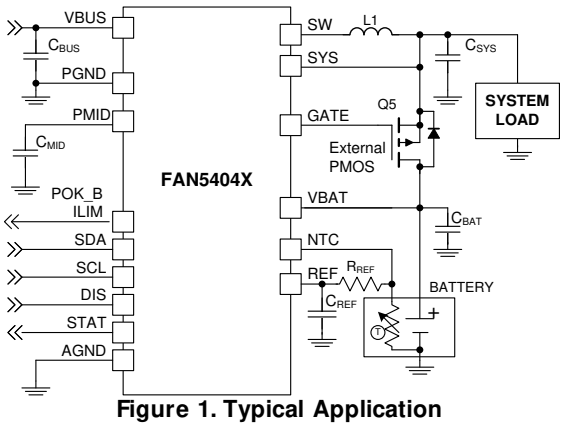


Figure 1. Typical Application

December-2017, Rev. 2

Publication Order Number:
FAN54041/D

Ordering Information

Part Number	Temperature Range	Package	PN Bits: IC_INFO[5:3]	Packing Method
FAN54040UCX	-40 to 85°C	25-Bump, Wafer-Level Chip-Scale Package (WLCSP), 0.4 mm Pitch	000	Tape and Reel
FAN54041UCX			001	
FAN54042UCX(1)			010	
FAN54045UCX(1)			101	
FAN54046UCX(1)			110	
FAN54047UCX			110	

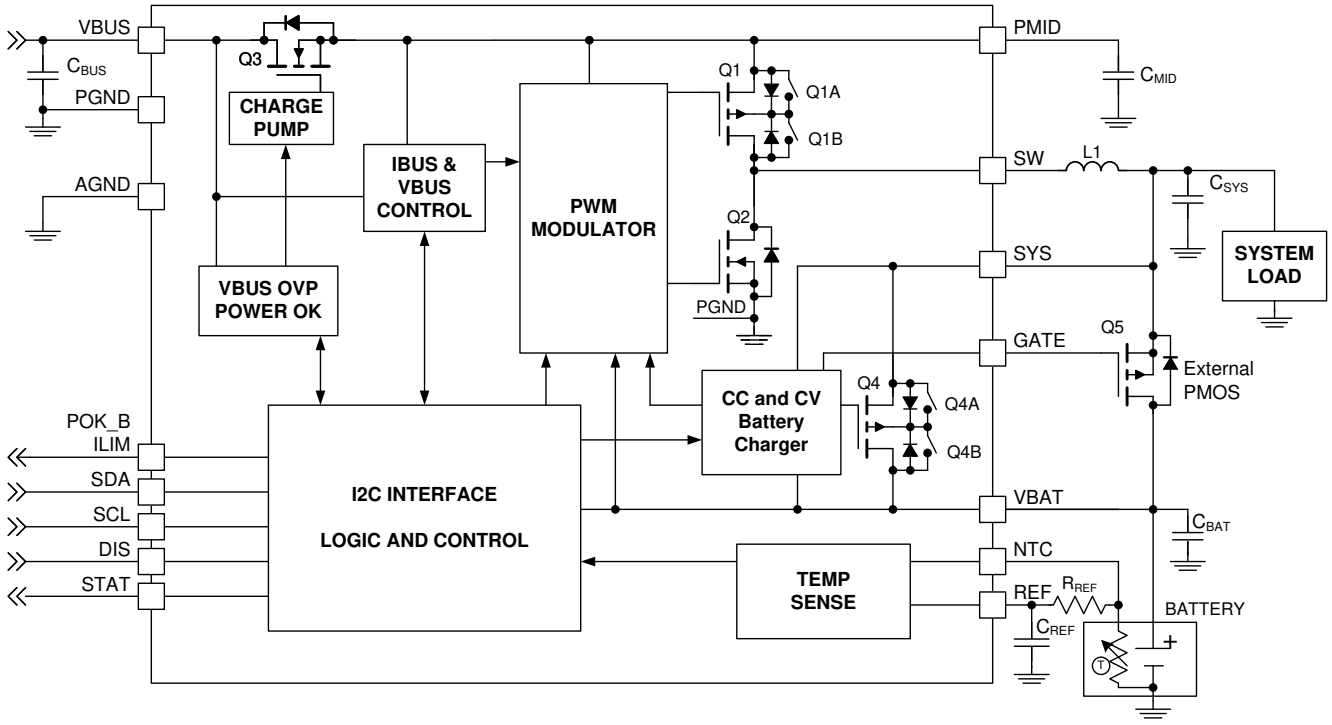
Note:

1. Contact ON Semiconductor Sales for availability.

Table 1. Feature Comparison Summary

Part Number	Slave Address	Automatic Charge	Battery Absent Behavior	E1 Pin
FAN54040	1101011	Yes	Off	POK_B
FAN54041	1101011	No	Off	POK_B
FAN54042	1101011	Yes	On	POK_B
FAN54045	1101011	No	Off	ILIM
FAN54046	1101011	No	On	ILIM
FAN54047	1101011	Yes	On	ILIM

Block Diagram



PMID	Q1A	Q1B
Greater than V_{BAT}	ON	OFF
Less than V_{BAT}	OFF	ON

SYS	Q4A	Q4B
Greater than V_{BAT}	ON	OFF
Less than V_{BAT}	OFF	ON

Figure 2. IC and System Block Diagram

Table 2. Recommended External Components

Component	Description	Vendor	Parameter	Typ.	Unit
L1	1 μH, 20%, 2.2 A, 2016	Taiyo Yuden MAKK2016T1R0M or Equivalent	L	1.0	μH
			DCR (Series R)	75	mΩ
C_{BAT}, C_{SYS}	10 μF, 20%, 6.3 V, X5R, 0603	Murata: GRM188R60J106M TDK: C1608X5R0J106M	C	10	μF
C_{MID}	4.7 μF, 10%, 6.3 V, X5R, 0603	Murata: GRM188R60J475K TDK: C1608X5R0J475K	C(2)	4.7	μF
C_{BUS},	1.0 μF, 10%, 25 V, X5R, 0603	Murata GRM188R61E105K TDK:C1608X5R1E105M	C	1.0	μF
Q5	PMOS,12 V, 16 mΩ, MLP2x2	ON Semiconductor FDMA905P	$R_{DS(ON)}$	16	mΩ
C_{REF}	1 μF, 10%, 6.3 V, X5R, 0402		C	1.0	μF

Note:

2. 6.3 V rating is sufficient for C_{MID} since PMID is protected from over-voltage surges on VBUS by Q3.

Pin Configuration

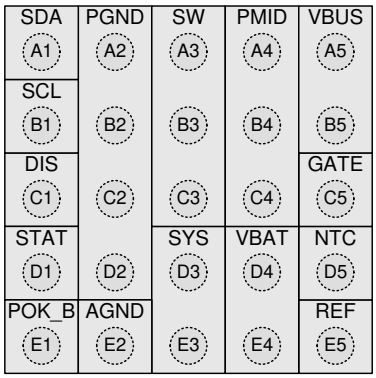


Figure 3. Top View

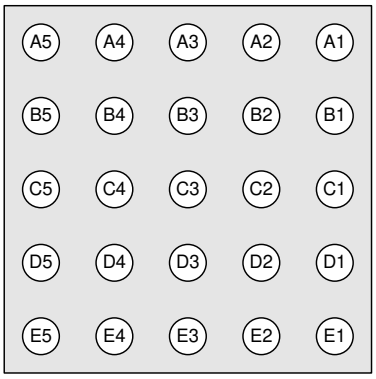


Figure 4. Bottom View

Pin Definitions

Pin #	Name	Description
A1	SDA	**I²C Interface Serial Data**. This pin should not be left floating.
B1	SCL	**I²C Interface Serial Clock**. This pin should not be left floating.
C1	DIS	**Disable**. If this pin is held HIGH, Q1 and Q3 are turned off, creating a HIGH Z condition at VBUS and the PWM converter is disabled.
D1	STAT	**Status**. Open-drain output indicating charge status. The IC pulls this pin LOW when charge is in progress; can be used to signal the host processor when a fault condition occurs.
E1	POK_B	**Power OK (FAN54040-2)**. Open-drain output that pulls LOW when VBUS is plugged in and the battery has risen above V_{LOWV}. This signal is used to signal the host processor that it can begin to draw significant current.
E1	ILIM	**Input Current Limit (FAN54045-7)**. Controls input current limit in Auto-Charge Mode. When LOW, input current is limited to 100 mA maximum. When HIGH, input current is limited to 500 mA. In 32-Second Mode, the input current limit is set by the I_{BUSLIM} bits.
A2 – D2	PGND	**Power Ground**. Power return for gate drive and power transistors. The connection from this pin to the bottom of C_{MID} should be as short as possible.
E2	AGND	**Analog Ground**. All IC signals are referenced to this node.
A3 – C3	SW	**Switching Node**. Connect to output inductor.
D3 – E3	SYS	**System Supply**. Output voltage of the switching charger and input to the power path controller. Bypass SYS to PGND with a 10 μF capacitor.
A4 – C4	PMID	**Power Input Voltage**. Power input to the charger regulator, bypass point for the input current sense. Bypass with a minimum of a 4.7 μF, 6.3 V capacitor to PGND.
D4 – E4	VBAT	**Battery Voltage**. Connect to the positive (+) terminal of the battery pack. Bypass with a 10 μF capacitor to PGND. VBAT is a power path connection.
A5 – B5	VBUS	**Charger Input Voltage** and USB-OTG output voltage. Bypass with a 1 μF capacitor to PGND.
C5	GATE	**External MOSFET Gate**. This pin controls the gate of an external P-channel MOSFET transistor used to augment the internal ideal diode. The source of the P-channel MOSFET should be connected to SYS and the drain should be connected to VBAT.
D5	NTC	**Thermistor input**. The IC compares this node with taps on a resistor divider from REF to inhibit auto-charging when the battery temperature is outside of permitted fast-charge limits.
E5	REF	**Reference Voltage**. REF is a 1.8 V regulated output.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter			Min.	Max.	Unit
V_{BUS}	Voltage on VBUS Pin	Continuous		-0.3	28.0	V
		Pulsed, 100 ms Maximum Non-Repetitive		-1.0		
V_I	Voltage on PMID Voltage Pin			–0.3	7.0	V
	Voltage on SW, SYS, VBAT, STAT, DIS Pins			–0.3	7.0	
V_O	Voltage on Other Pins			–0.3	6.5[3]	V
$\frac{dV_{BUS}}{dt}$	Maximum V_{BUS} Slope Above 5.5 V when Boost or Charger Active				4	V/μs
ESD	Electrostatic Discharge Protection Level	Human Body Model per JESD22-A114		2000		V
		Charged Device Model per JESD22-C101		500		
	IEC 61000-4-2 System ESD[4]	USB Connector Pins (V_{BUS} to GND)	Air Gap	15		kV
			Contact	8		
T_J	Junction Temperature			–40	+150	°C
T_{STG}	Storage Temperature			–65	+150	°C
T_L	Lead Soldering Temperature, 10 Seconds				+260	°C

Note:

3. Lesser of 6.5 V or V_I + 0.3 V.
4. Guaranteed if C_{BUS} ≥1 μF and C_{MID} ≥ 4. 7μF.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. ON Semiconductor does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter		Min.	Max.	Unit
V_{BUS}	Supply Voltage		4	6	V
$V_{BAT(MAX)}$	Maximum Battery Voltage when Boost enabled			4.5	V
$-\frac{dV_{BUS}}{dt}$	Negative VBUS Slew Rate during VBUS Short Circuit, C_{MID} ≤ 4.7 μF, *see VBUS Short While Charging*	T_A ≤ 60°C		4	V/μs
		T_A ≥ 60°C		2	
T_A	Ambient Temperature		–30	+85	°C
T_J	Junction Temperature *(see Thermal Regulation and Protection section)*		–30	+120	°C

Thermal Properties

Junction-to-ambient thermal resistance is a function of application and board layout. This data is measured with four-layer 2s2p boards in accordance to JEDEC standard JESD51. Special attention must be paid not to exceed junction temperature $T_{J(max)}$ at a given ambient temperature T_A. *For measured data, see Table 18.*

Symbol	Parameter	Typical	Unit
θ_{JA}	Junction-to-Ambient Thermal Resistance *(see also Figure 18)*	50	°C/W
θ_{JB}	Junction-to-PCB Thermal Resistance	20	°C/W

Electrical Specifications

Unless otherwise specified: according to the circuit of Figure 1; recommended operating temperature range for T_J and T_A; V_{BUS}=5.0 V; HZ_MODE; OPA_MODE=0; (Charge Mode); SCL, SDA=0 or 1.8 V; and typical values are for T_J=25°C.

Symbol	Parameter	Conditions		Min.	Typ.	Max.	Unit
Power Supplies							
I_{VBUS}	VBUS Current	$V_{BUS} > V_{BUS(min)}$, PWM Switching			10		mA
		$V_{BUS} > V_{BUS(min)}$; $V_{BAT} > V_{OREG}$ I_{BUSLIM}=100 mA			2.5		mA
		0°C < T_J < 85°C, HZ_MODE=1 $V_{BAT} < V_{LOWV}$, 32S Mode, I_{REG}=0				280	µA
I_{BAT_HZ}	Battery Discharge Current in High-Impedance Mode	DIS=1, or HZ_MODE=1, V_{BUS}=0, 5 V or Floating, V_{BAT}=4.2 V			<1	10	µA
I_{BUS_HZ}	Battery Leakage Current to V_{BUS} in High-Impedance Mode	DIS=1, or HZ_MODE=1, V_{BUS} Shorted to Ground, V_{BAT}=4.2 V		-5.0	-0.2		µA
Charger Voltage Regulation							
V_{OREG}	Charge Voltage Range			3.5		4.4	V
	Charge Voltage Accuracy	T_A=25°C		–0.5		+0.5	%
		T_J=0 to 125°C		–1		+1	%
Charging Current Regulation							
I_{OCHRG}	Output Charge Current Range	$V_{LOWV} < V_{BAT} < V_{OREG}$	IO_LEVEL=0	550		1550	mA
			IO_LEVEL=1	290	340	390	mA
	Charge Current Accuracy	IO_LEVEL=0		–5		+5	%
Weak Battery Detection							
V_{LOWV}	Weak Battery Threshold Range			3.4		3.7	V
	Weak Battery Threshold Accuracy			–5		+5	%
	Weak Battery Deglitch Time	Rising Voltage, 2 mV Overdrive			30		ms
Logic Levels : DIS, SDA, SCL							
V_{IH}	High-Level Input Voltage			1.05			V
V_{IL}	Low-Level Input Voltage					0.4	V
I_{IN}	Input Bias Current	Input Tied to GND or V_{BUS}			0.01	1.00	µA
Charge Termination Detection							
$I_{(TERM)}$	Termination Current Range	$V_{BAT} > V_{OREG} – V_{RCH}$, $V_{BUS} > V_{SLP}$		50		400	mA
	Termination Current Accuracy	I_{TERM} Setting ≤ 100 mA		–15		+15	%
		I_{TERM} Setting ≥ 200 mA		–5		+5	
	Termination Current Deglitch Time				30		ms
Power Path (Q4) Control							
I_{LIN}	Power Path Max. Charge Current		IO_LEVEL=1	290	340	390	mA
		I_{BUSLIM} > 01, $I_{OCHARGE}$ ≤ 02	IO_LEVEL=0	400	450	510	mA
		I_{BUSLIM} > 01, $I_{OCHARGE}$ > 02	IO_LEVEL=0	650	725	800	mA
V_{THSYS}	VBAT to SYS Threshold for Q4 and Gate Transition While Charging	(SYS-VBAT) Falling		–6	–5	–3	mV
		(SYS-VBAT) Rising		-1	+1	2	mV
Production Test Mode							
$V_{BAT(PTM)}$	Production Test Output Voltage	1 mA < I_{BAT} < 2 A, V_{BUS}=5.5 V		4.116	4.200	4.284	V
$I_{BAT(PTM)}$	Production Test Output Current	20% Duty with Max. Period 10 ms		2.3			A

Continued on the following page…

Electrical Specifications (Continued)

Unless otherwise specified: according to the circuit of Figure 1; recommended operating temperature range for T_J and T_A; V_{BUS}=5.0 V; HZ_MODE; OPA_MODE=0; (Charge Mode); SCL, SDA=0 or 1.8 V; and typical values are for T_J=25°C.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
Input Power Source Detection						
T1	T1 (0°C) Temperature Threshold		71.9	73.9	75.9	% of V_{REF}
T2	T1 (10°C) Temperature Threshold		62.6	64.6	66.6	
T3	T1 (45°C) Temperature Threshold		31.9	32.9	34.9	
T4	T1 (60°C) Temperature Threshold		21.3	23.3	25.3	
Input Power Source Detection						
$V_{IN(MIN)1}$	VBUS Input Voltage Rising	To Initiate and Pass VBUS Validation		4.29	4.42	V
$V_{IN(MIN)2}$	Minimum VBUS during Charge	During Charging		3.71	3.94	V
t_{VBUS_VALID}	VBUS Validation Time			30		ms
V_{BUS} Control Loop						
V_{BUSLIM}	VBUS Loop Setpoint Accuracy		–3		+3	%
Input Current Limit						
I_{BUSLIM}	Charger Input Current Limit Threshold	I_{BUSLIM} Set to 100 mA	88	93	98	mA
		I_{BUSLIM} Set to 500 mA	450	475	500	
V_{REF} Bias Generator						
V_{REF}	Bias Regulator Voltage	$V_{BUS} > V_{IN(MIN)}$		1.8		V
	Short-Circuit Current Limit			2.5		mA
Battery Recharge Threshold						
V_{RCH}	Recharge Threshold	Below $V_{(OREG)}$	100	120	150	mV
	Deglitch Time	V_{BAT} Falling Below V_{RCH} Threshold		130		ms
STAT, POK_B Output						
$V_{STAT(OL)}$	STAT Output Low	I_{STAT}=10 mA			0.4	V
$I_{STAT(OH)}$	STAT High Leakage Current	V_{STAT}=5 V			1	μA
Battery Detection						
I_{DETECT}	Battery Detection Current before Charge Done (Sink Current)[5]	Begins after Termination Detected and $V_{BAT} \le V_{OREG} - V_{RCH}$		–0.8		mA
t_{DETECT}	Battery Detection Time			262		ms
Sleep Comparator						
V_{SLP}	Sleep-Mode Entry Threshold, $V_{BUS} - V_{BAT}$	2.3 V ≤ V_{BAT} ≤ V_{OREG}, V_{BUS} Falling	0	0.04	0.10	V
Power Switches *(see Figure 2)*						
$R_{DS(ON)}$	Q3 On Resistance (VBUS to PMID)	$I_{IN(LIMIT)}$=500 mA		180	250	mΩ
	Q1 On Resistance (PMID to SW)			130	225	
	Q2 On Resistance (SW to GND)			150	225	
	Q4 On Resistance (SYS to VBAT)	V_{BAT}=4.2 V		70	100	mΩ
I_{SYNC}	Synchronous to Non-Synchronous Current Cut-Off Threshold[6]	Low-Side MOSFET (Q2) Cycle-by-Cycle Current Limit		140		mA

Continued on the following page…

Electrical Specifications (Continued)

Unless otherwise specified: according to the circuit of Figure 1; recommended operating temperature range for T_J and T_A; V_{BUS}=5.0 V; HZ_MODE; OPA_MODE=0; (Charge Mode); SCL, SDA=0 or 1.8 V; and typical values are for T_J=25°C.

Symbol	Parameter	Conditions		Min.	Typ.	Max.	Unit
Charger PWM Modulator							
f_{SW}	Oscillator Frequency			2.7	3.0	3.3	MHz
D_{MAX}	Maximum Duty Cycle					100	%
D_{MIN}	Minimum Duty Cycle				0		%
Boost Mode Operation (OPA_MODE=1, HZ_MODE=0)							
V_{BOOST}	Boost Output Voltage at VBUS	2.5 V < V_{BAT} < 4.5 V, I_{LOAD} from 0 to 200 mA		4.80	5.07	5.20	V
		3.0 V < V_{BAT} < 4.5 V, I_{LOAD} from 0 to 500 mA		4.77	5.07	5.20	
$I_{BAT(BOOST)}$	Boost Mode Quiescent Current	PFM Mode, V_{BAT}=3.6 V, I_{LOAD}=0			250	350	μA
$I_{LIMPK(BST)}$	Q2 Peak Current Limit			1350	1550	1950	mA
$UVLO_{BST}$	Minimum Battery Voltage for Boost Operation	While Boost Active			2.32		V
		To Start Boost Regulator			2.48	2.70	
VBUS Load Resistance							
R_{VBUS}	VBUS to PGND Resistance	Normal Operation			500		kΩ
		VBUS Validation			100		Ω
Protection and Timers							
$VBUS_{OVP}$	VBUS Over-Voltage Shutdown	V_{BUS} Rising		6.09	6.29	6.49	V
	Hysteresis	V_{BUS} Falling			100		mV
$I_{LIMPK(CHG)}$	Q1 Cycle-by-Cycle Peak Current Limit	Charge Mode			3		A
V_{SHORT}	Battery Short-Circuit Threshold	V_{BAT} Rising		1.95	2.00	2.05	V
	Hysteresis				100		mV
I_{SHORT}	Linear Charging Current	V_{BAT} < V_{SHORT}	Power Path		13		mA
			Linear		30		
$T_{SHUTDWN}$	Thermal Shutdown Threshold[7]	T_J Rising			145		°C
	Hysteresis[7]	T_J Falling			25		
T_{CF}	Thermal Regulation Threshold[7]	Charge Current Reduction Begins			120		°C
t_{INT}	Detection Interval				2.1		s
t_{32S}	32-Second Timer[8]	Charger Enabled		20.5	25.2	28.0	s
		Charger Disabled		18.0	25.2	34.0	
t_{15MIN}	15-Minute Timer	15-Minute Mode (FAN54040, FAN54042, FAN54046, FAN54047)		12.0	13.5	15.0	min
Δt_{LF}	Low-Frequency Timer Accuracy	Charger Inactive		–25		25	%

Notes:

5. Negative current is current flowing from the battery to VBUS (discharging the battery).
6. Q2 always turns on for 60 ns, then turns off if current is below I_{SYNC}.
7. Guaranteed by design; not tested in production.
8. This tolerance (%) applies to all timers on the IC, including soft-start and deglitching timers.

I²C Timing Specifications

Guaranteed by design.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
f_{SCL}	SCL Clock Frequency	Standard Mode			100	kHz
		Fast Mode			400	
		Fast Mode Plus			1000	
		High-Speed Mode, $C_B \leq 100$ pF			3400	
		High-Speed Mode, $C_B \leq 400$ pF			1700	
t_{BUF}	BUS-free Time between STOP and START Conditions	Standard Mode		4.7		µs
		Fast Mode		1.3		
		Fast Mode Plus		0.5		
$t_{HD;STA}$	START or Repeated START Hold Time	Standard Mode		4		µs
		Fast Mode		600		ns
		Fast Mode Plus		260		ns
		High-Speed Mode		160		ns
t_{LOW}	SCL LOW Period	Standard Mode		4.7		µs
		Fast Mode		1.3		µs
		Fast Mode Plus		0.5		µs
		High-Speed Mode, $C_B \leq 100$ pF		160		ns
		High-Speed Mode, $C_B \leq 400$ pF		320		ns
t_{HIGH}	SCL HIGH Period	Standard Mode		4		µs
		Fast Mode		600		ns
		Fast Mode Plus		260		ns
		High-Speed Mode, $C_B \leq 100$ pF		60		ns
		High-Speed Mode, $C_B \leq 400$ pF		120		ns
$t_{SU;STA}$	Repeated START Setup Time	Standard Mode		4.7		µs
		Fast Mode		600		ns
		Fast Mode Plus		260		ns
		High-Speed Mode		160		ns
$t_{SU;DAT}$	Data Setup Time	Standard Mode		250		ns
		Fast Mode		100		
		Fast Mode Plus		50		
		High-Speed Mode		10		
$t_{HD;DAT}$	Data Hold Time	Standard Mode	0		3.45	µs
		Fast Mode	0		900	ns
		Fast Mode Plus	0		450	ns
		High-Speed Mode, $C_B \leq 100$ pF	0		70	ns
		High-Speed Mode, $C_B \leq 400$ pF	0		150	ns
t_{RCL}	SCL Rise Time	Standard Mode	$20+0.1C_B$		1000	ns
		Fast Mode	$20+0.1C_B$		300	
		Fast Mode Plus	$20+0.1C_B$		120	
		High-Speed Mode, $C_B \leq 100$ pF		10	80	
		High-Speed Mode, $C_B \leq 400$ pF		20	160	

Continued on the following page…

I^2C Timing Specifications (Continued)

Guaranteed by design.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
t_{FCL}	SCL Fall Time	Standard Mode		$20+0.1C_B$	300	ns
		Fast Mode		$20+0.1C_B$	300	
		Fast Mode Plus		$20+0.1C_B$	120	
		High-Speed Mode, $C_B \leq 100$ pF		10	40	
		High-Speed Mode, $C_B \leq 400$ pF		20	80	
t_{RCL1}	Rise Time of SCL after a Repeated START Condition and after ACK Bit	High-Speed Mode, $C_B \leq 100$ pF		10	80	ns
		High-Speed Mode, $C_B \leq 400$ pF		20	160	
t_{RDA}	SDA Rise Time	Standard Mode		$20+0.1C_B$	1000	ns
		Fast Mode		$20+0.1C_B$	300	
		Fast Mode Plus		$20+0.1C_B$	120	
		High-Speed Mode, $C_B \leq 100$ pF		10	80	
		High-Speed Mode, $C_B \leq 400$ pF		20	160	
t_{FDA}	SDA Fall Time	Standard Mode		$20+0.1C_B$	300	ns
		Fast Mode		$20+0.1C_B$	300	
		Fast Mode Plus		$20+0.1C_B$	120	
		High-Speed Mode, $C_B \leq 100$ pF		10	80	
		High-Speed Mode, $C_B \leq 400$ pF		20	160	
$t_{SU;STO}$	Stop Condition Setup Time	Standard Mode		4		μs
		Fast Mode		600		ns
		Fast Mode Plus		120		ns
		High-Speed Mode		160		ns
C_B	Capacitive Load for SDA and SCL				400	pF

Timing Diagrams

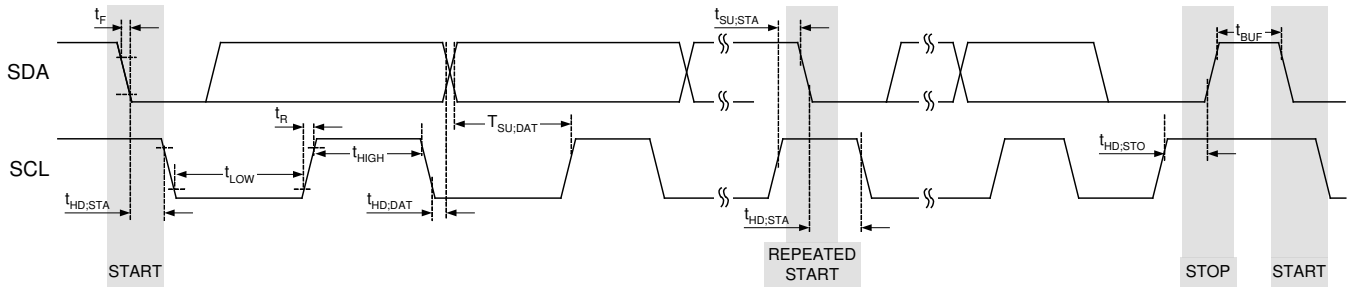
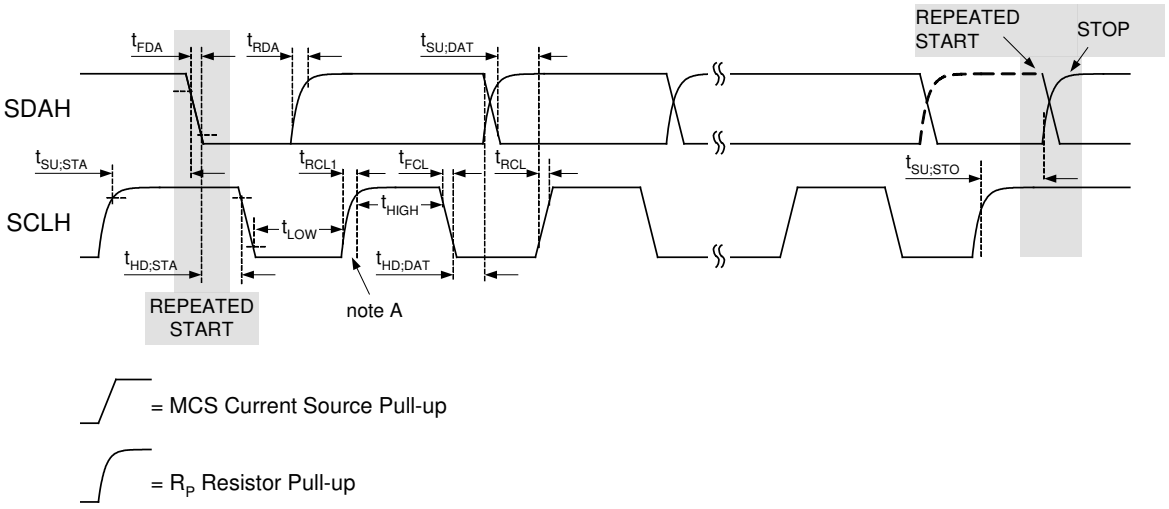


Figure 5. I²C Interface Timing for Fast and Slow Modes



Note A: First rising edge of SCLH after Repeated Start and after each ACK bit.

Figure 6. I²C Interface Timing for High-Speed Mode

Charge Mode Typical Characteristics

Unless otherwise specified, circuit of Figure 1, V_{OREG}=4.2 V, V_{BUS}=5.0 V, and T_A=25°C.

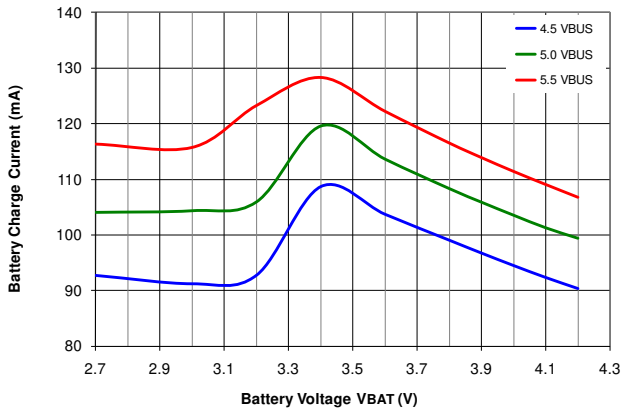


Figure 7. Battery Charge Current vs. V_{BUS} with I_{BUSLIM}=100 mA

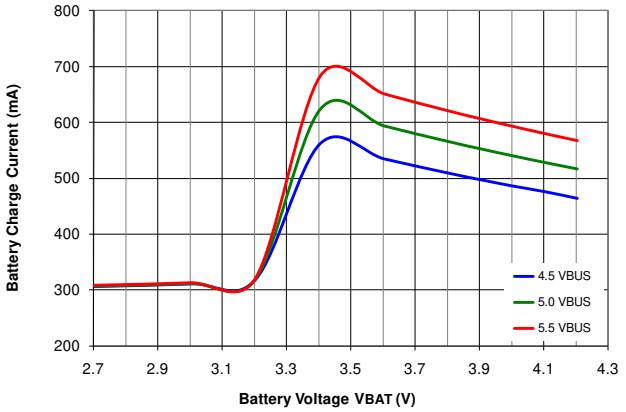


Figure 8. Battery Charge Current vs. V_{BUS} with I_{BUSLIM}=500 mA

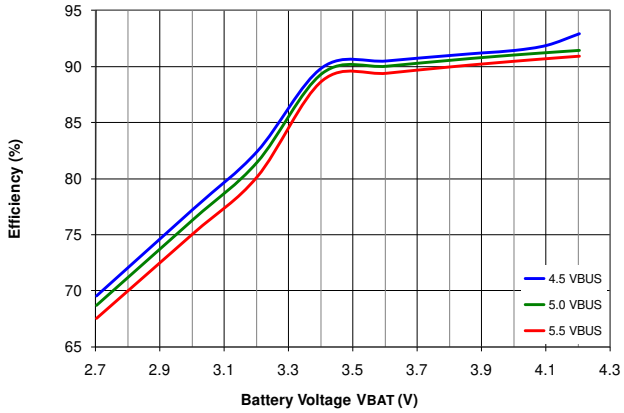


Figure 9. Efficiency vs. V_{BUS}, I_{BUSLIM}=500 mA, I_{SYS}=0

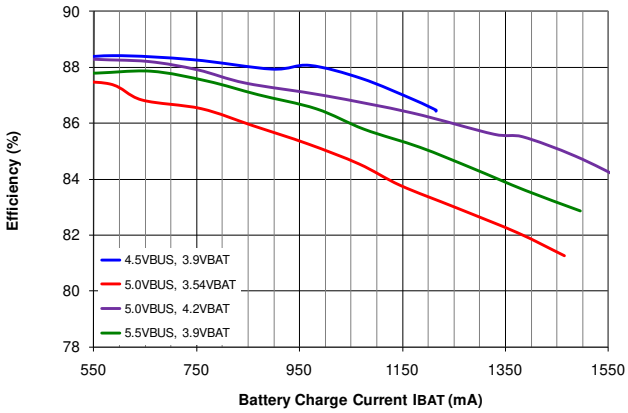


Figure 10. Efficiency vs. Charging Current, I_{BUSLIM}=No Limit

Charge Mode Typical Characteristics

Unless otherwise specified, circuit of Figure 1, V_{OREG}=4.2 V, V_{BUS}=5.0 V, and T_A=25°C.

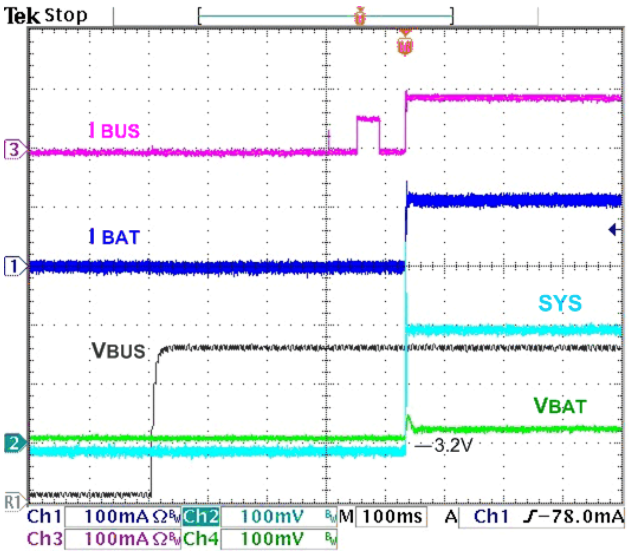


Figure 11. Charger Startup at V_{BUS} Plug-In, 100 mA I_{BUSLIM}, 3.2 V_{BAT}, 100 Ω SYS Load

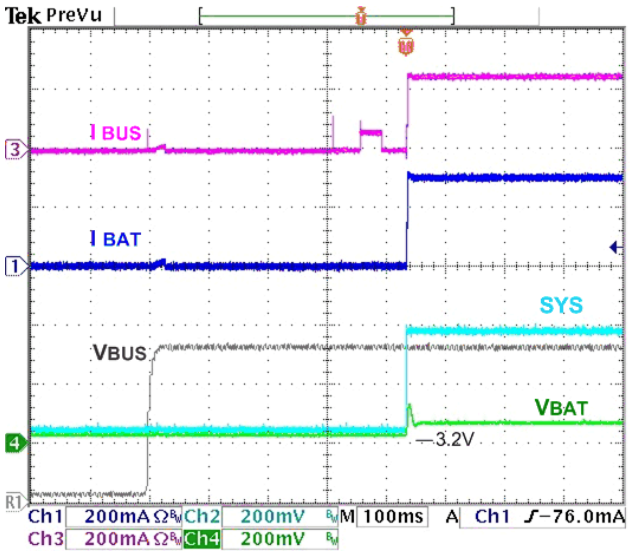


Figure 12. Charger Startup at V_{BUS} Plug-In, 500 mA $I_{INBUSLIM}$, 3.2 V_{BAT}, 100 Ω SYS Load

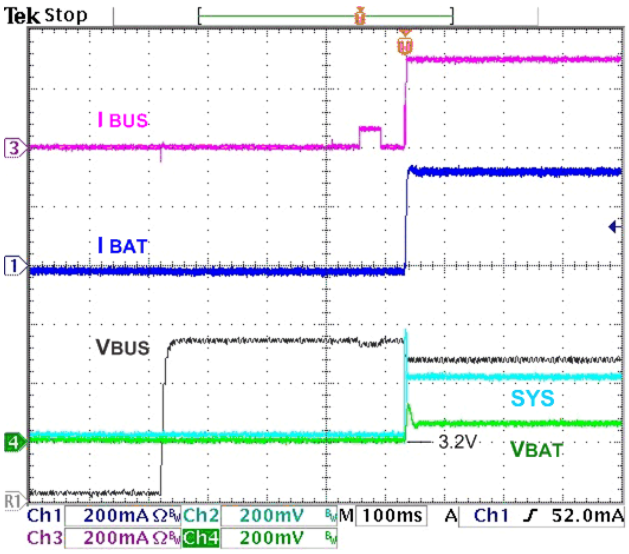


Figure 13. Charger Startup at V_{BUS} Plug-In Using 300 mA Current Limited Source, 500 mA I_{BUSLIM}, 3.2 V_{BAT}, 50 Ω SYS Load

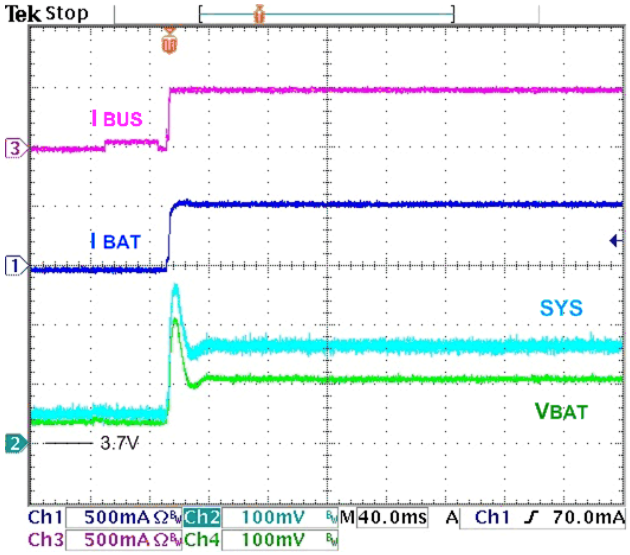


Figure 14. Charger Startup with HZ Bit Reset, 500 mA I_{BUSLIM}, 950 mA I_{CHARGE}, 50 Ω SYS Load

Charge Mode Typical Characteristics

Unless otherwise specified, circuit of Figure 1, V_{OREG}=4.2 V, V_{BUS}=5.0 V, and T_A=25°C.

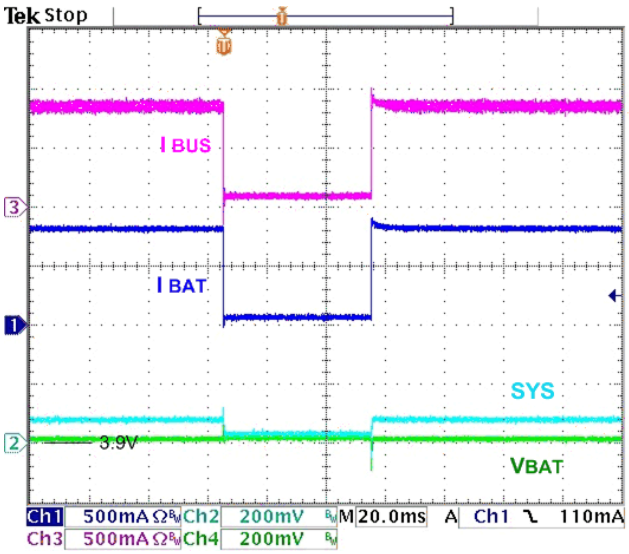


Figure 15. Battery Removal / Insertion while Charging, TE=0, 3.9 V_{BAT}, I_{CHRG}=950 mA, I_{BUSLIM}=No Limit, 50 Ω SYS Load

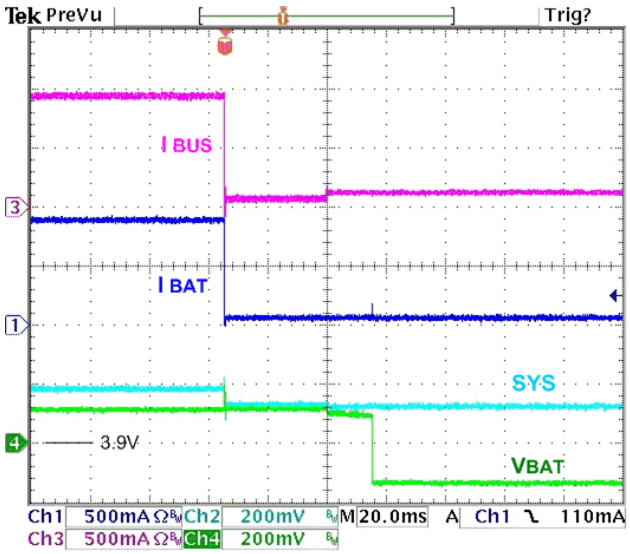


Figure 16. Battery Removal / Insertion when Charging, TE=1, 3.9 V_{BAT}, I_{CHRG}=950 mA, I_{BUSLIM}=No Limit, 50 Ω SYS Load

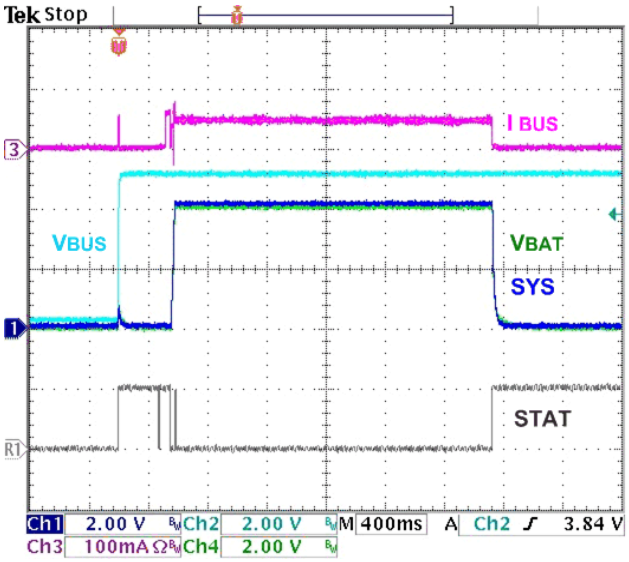


Figure 17. No Battery at V_{BUS} Power-Up, FAN54040, 100 Ω SYS Load, 1 kΩ V_{BAT} Load

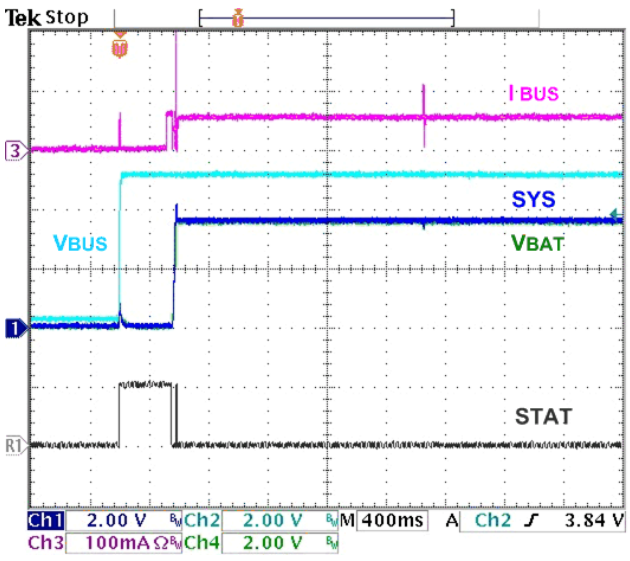


Figure 18. No Battery at V_{BUS} Power-Up, FAN54042, 100 Ω SYS Load, 1 kΩ V_{BAT} Load

Charge Mode Typical Characteristics

Unless otherwise specified, circuit of Figure 1, V_{OREG}=4.2 V, V_{BUS}=5.0 V, and T_A=25°C.

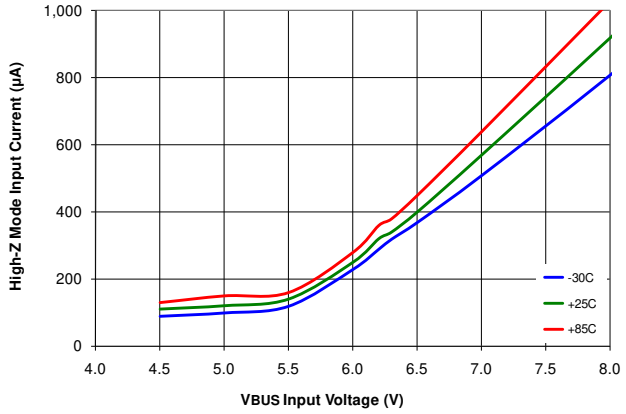


Figure 19. HZ Mode VBUS Current vs. Temperature, 3.7 V_{BAT}

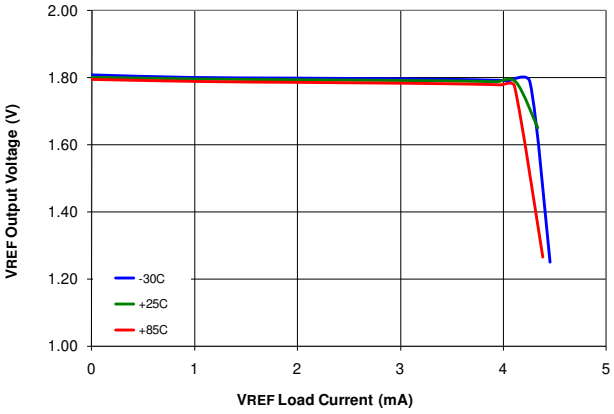


Figure 20. V_{REF} vs. Load Current, Over-Temperature, 5.0 V_{BUS}

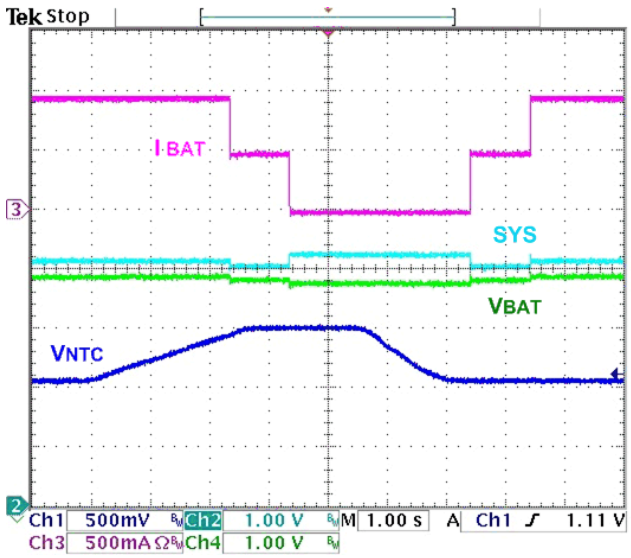


Figure 21. Charging vs. Temperature (NTC), +30°C to -10°C 3.7 V_{BAT}, I_{CHRG}=950 mA, No I_{BUSLIM}, 100 Ω SYS Load

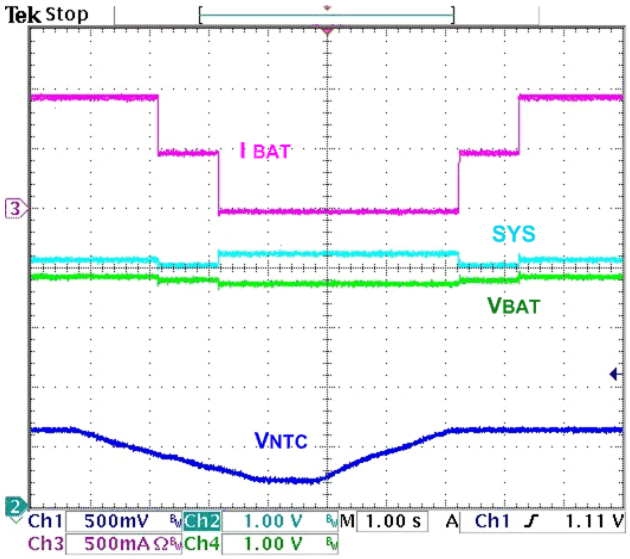


Figure 22 Charging vs. Temperature (NTC), +30°C to +70°C 3.7 V_{BAT}, I_{CHRG}=950 mA, No I_{BUSLIM}, 100 Ω SYS Load

GSM Typical Characteristics

A 2.0 A GSM pulse applied at VBAT with 5 µs rise / fall time. Simultaneous to GSM pulse, 50 Ω additional load applied at SYS.

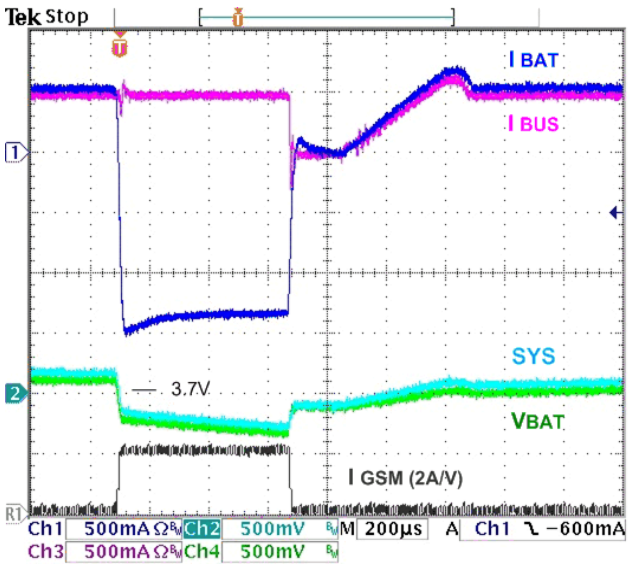


Figure 23. 2.0 A GSM Pulse Response, I_{BUSLIM}=500 mA Control, I_{CHRG}=950 mA, 3.7 V_{BAT}, OREG=4.2 V

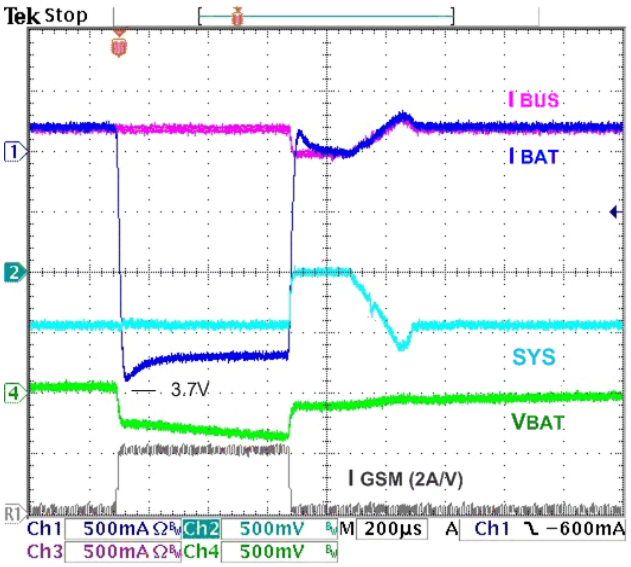


Figure 24. 2.0 A GSM Pulse Response, I_{BUSLIM}=500 mA, I_{CHRG}=950 mA, 3.7 V_{BAT}, OREG=4.2 V, 200 mA Source Current Limit

Boost Mode Typical Characteristics

Unless otherwise specified, using circuit of Figure 1, V_{BAT}=3.6 V, T_A=25°C.

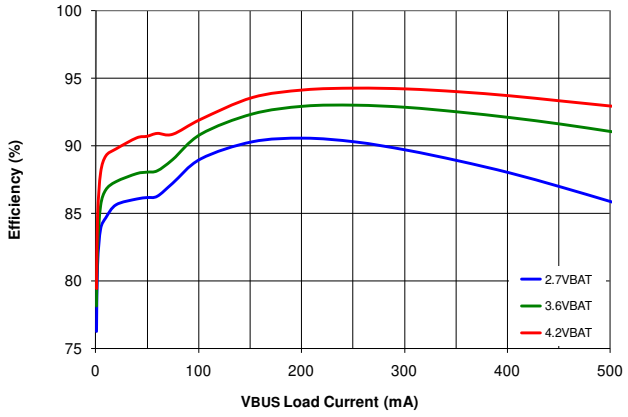


Figure 25. Efficiency vs. I_{BUS} Over V_{BAT}

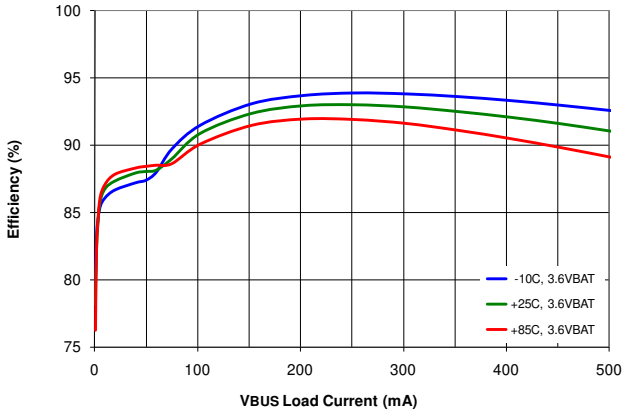


Figure 26. Efficiency vs. I_{BUS} Over-Temperature, 3.6 V_{BAT}

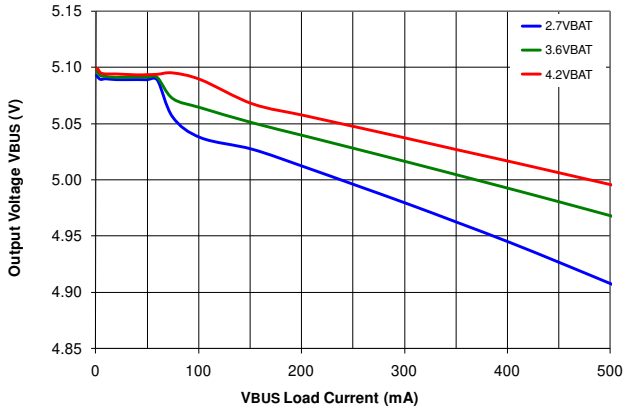


Figure 27. Regulation vs. I_{BUS} Over V_{BAT}

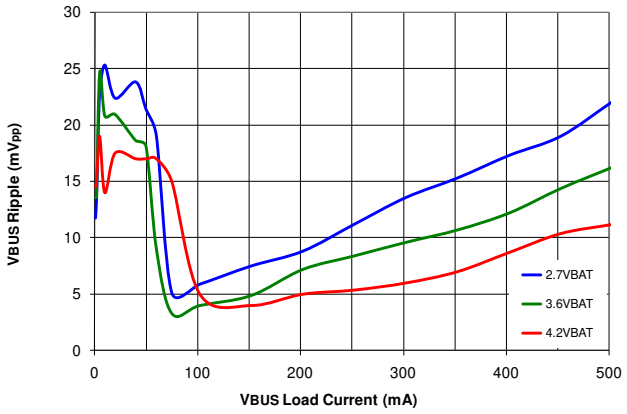


Figure 28. Output Ripple vs. I_{BUS} Over V_{BAT}

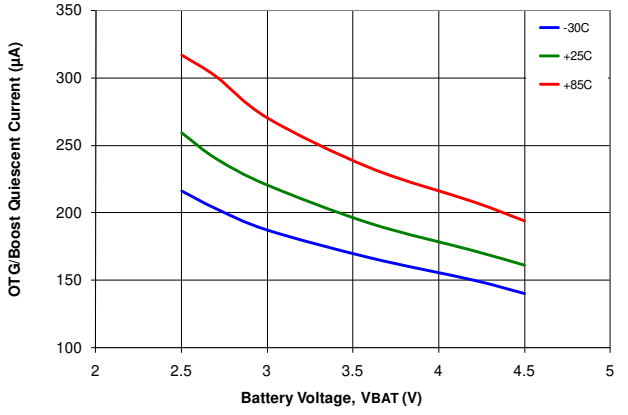


Figure 29. Quiescent Current (I_Q) vs. V_{BAT} Over-Temperature

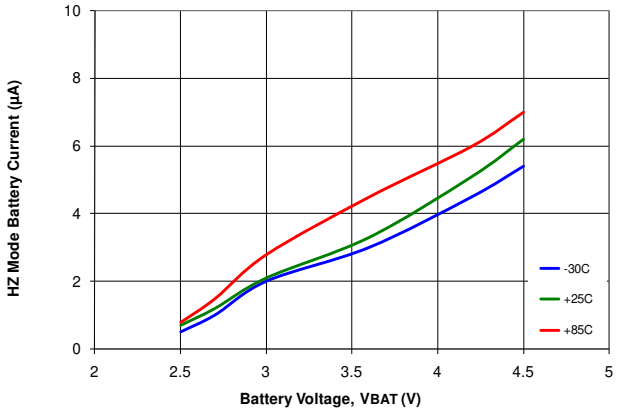


Figure 30. Battery Discharge Current vs. V_{BAT}, HZ / Sleep Mode

Boost Mode Typical Characteristics

Unless otherwise specified, using circuit of Figure 1, V_{BAT}=3.6 V, T_A=25°C.

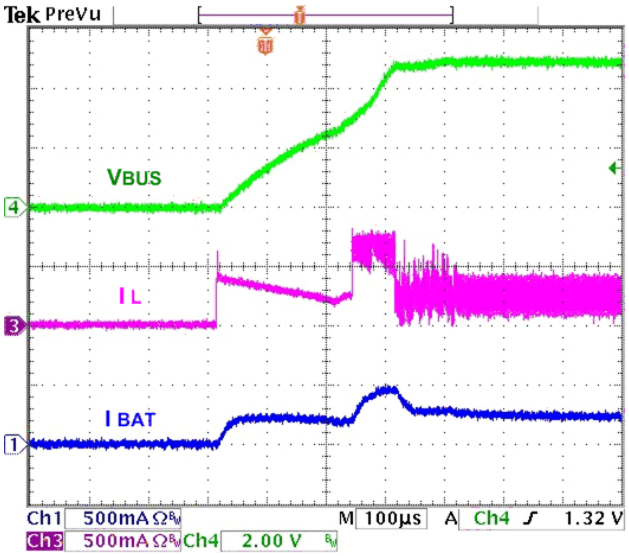


Figure 31. OTG Startup, 50 Ω Load, 3.6 V_{BAT} External / Additional 10 µf on VBUS

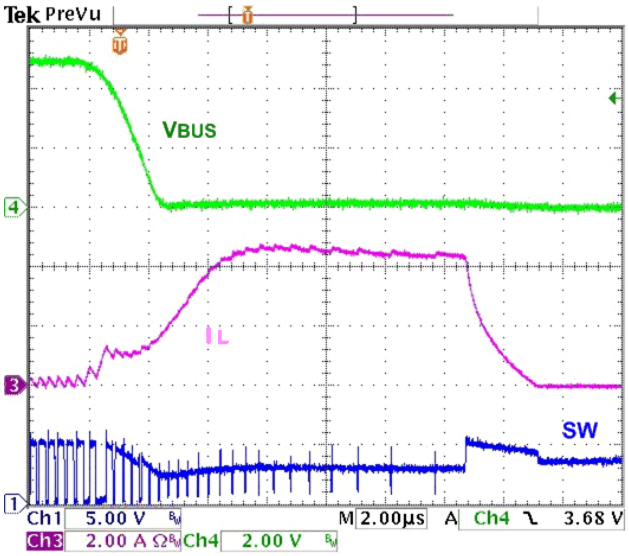


Figure 32. OTG V_{BUS} Overload Response

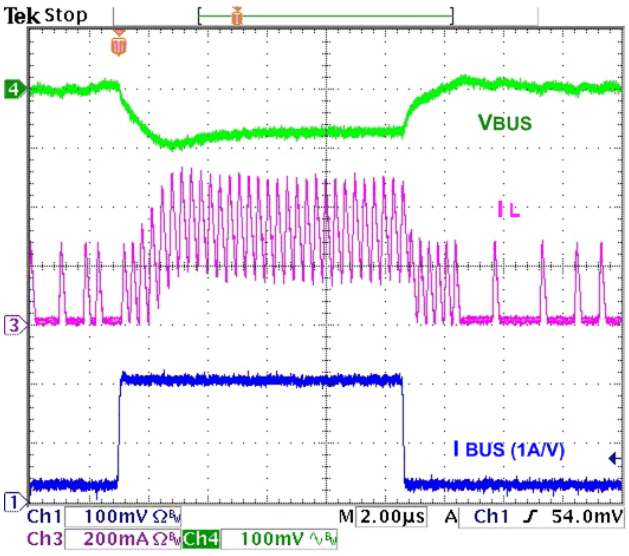


Figure 33. Load Transient, 20-200-20 mA I_{BUS}, $t_{RISE/FALL}$=100 ns

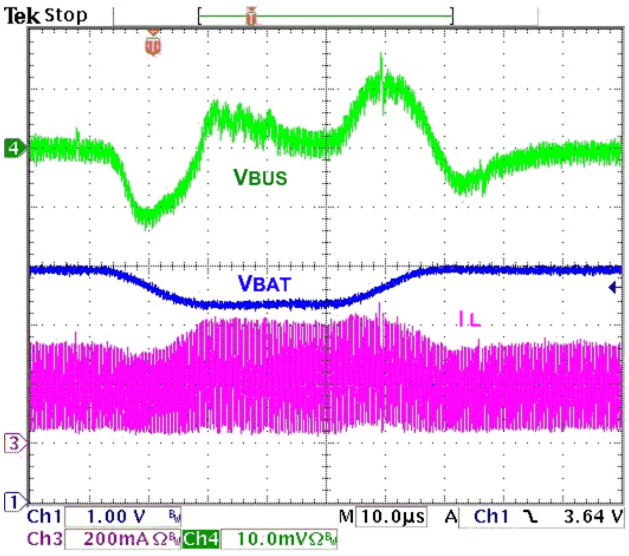


Figure 34. Line Transient, 50 Ω Load, 3.9-3.3-3.9 V_{BAT}, $t_{RISE/FALL}$=10 µs

Circuit Description / Overview

When charging batteries with a current-limited input source, such as USB, a switching charger's high efficiency over a wide range of output voltages minimizes charging time.

FAN5404X combines a highly integrated synchronous buck regulator for charging with a synchronous boost regulator, which can supply 5 V to USB On-The-Go (OTG) peripherals. The FAN5404X employs synchronous rectification for both the charger and boost regulators to maintain high efficiency over a wide range of battery voltages and charge states.

The FAN5404X has four operating modes:

1. Charge Mode:
   Charges a single-cell Li-ion or Li-polymer battery.
2. Boost Mode:
   Provides 5 V power to USB-OTG with an integrated synchronous rectification boost regulator, using the battery as input.
3. High-Impedance Mode:
   Both the boost and charging circuits are OFF in this mode. Current flow from VBUS to the battery or from the battery to VBUS is blocked in this mode. This mode consumes very little current from VBUS or the battery.
4. Production Test Mode
   This mode provides 4.2 V output on VBAT and supplies a load current of up to 2.3 A.

Charge Mode

In Charge Mode, FAN5404X employs six regulation loops:

1. Input Current: Limits the amount of current drawn from VBUS. This current is sensed internally and can be programmed through the I^2C interface.
2. Charging Current: Limits the maximum charging current. This current is sensed using an internal sense MOSFET.
3. VBUS Voltage: This loop is designed to prevent the input supply from being dragged below V_{BUSLIM} (typically 4.5 V) when the input power source is current limited. An example of this would be a travel charger. This loop cuts back the current when V_{BUS} approaches V_{BUSLIM}, allowing the input source to run in current limit.
4. Charge Voltage: The regulator is restricted from exceeding this voltage. As the internal battery voltage rises, the battery's internal impedance works in conjunction with the charge voltage regulation to decrease the amount of current flowing to the battery. Battery charging is completed when the current through Q4 drops below the I_{TERM} threshold.
5. Power Path: When V_{BAT} is below V_{BATMIN}, Q4 operates as a linear current source and modulates its current to ensure that the voltage on SYS stays above 3.4 V.
6. Temperature: If the IC's junction temperature reaches 120°C, charge current is reduced until the IC's temperature is below 120°C.

Battery Charging Curve

If the battery voltage is below V_{SHORT}, a linear current source pre-charges the battery until V_{BAT} reaches V_{SHORT}. The PWM charging circuit is then started and the battery is charged with a constant current if sufficient input power is available. The current slew rate is limited to prevent overshoot.

The FAN5404X is designed to work with a current-limited input source at VBUS. During the current regulation phase of charging, I_{BUSLIM} or the programmed charging current limits the amount of current available to charge the battery and power the system. The effect of I_{BUSLIM} on I_{CHARGE} can be seen in Figure 36.

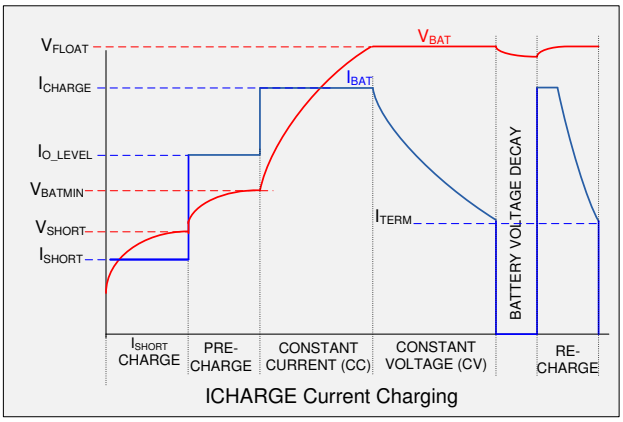


Figure 35. Charge Curve, I_{CHARGE} Not Limited by I_{INLIM}

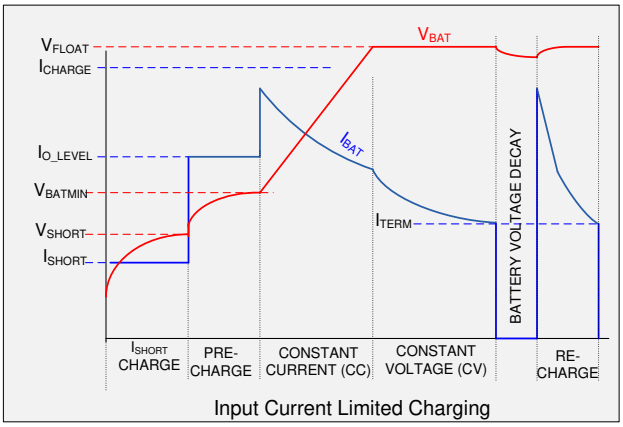


Figure 36. Charge Curve, I_{BUSLIM} Limits I_{CHARGE}

Assuming that V_{OREG} is programmed to the cell's fully charged "float" voltage, the current that the battery accepts with the PWM regulator limiting its output (sensed at VBAT) to V_{OREG} declines and the charger enters the voltage regulation phase of charging. When the current declines to the programmed I_{TERM} value, the charge cycle is complete. Charge current termination can be disabled by resetting the TE bit (REG1[3]).

The charger output or "float" voltage can be programmed by the OREG bits from 3.5 V to 4.44 V in 20 mV increments, as shown in Table 4.

The following charging parameters can be programmed by the host through I²C:

Table 3. Programmable Charging Parameters

Parameter	Name	Register
Output Voltage Regulation	V_{OREG}	REG2[7:2]
Battery Charging Current Limit	I_{OCHRG}	REG4[6:3]
Input Current Limit	I_{INLIM}	REG1[7:6]
Charge Termination Limit	I_{TERM}	REG4[2:0]
Weak Battery Voltage	V_{LOWV}	REG1[5:4]

Table 4. OREG Bits (OREG[7:2]) vs. Charger V_{OUT} (V_{OREG}) Float Voltage

Decimal	Hex	VOREG	Decimal	Hex	VOREG
0	00	3.50	24	18	3.98
1	01	3.52	25	19	4.00
2	**02**	**3.54**	26	1A	4.02
3	03	3.56	27	1B	4.04
4	04	3.58	28	1C	4.06
5	05	3.60	29	1D	4.08
6	06	3.62	30	1E	4.10
7	07	3.64	31	1F	4.12
8	08	3.66	32	20	4.14
9	09	3.68	33	21	4.16
10	0A	3.70	34	22	4.18
11	0B	3.72	35	23	4.20
12	0C	3.74	36	24	4.22
13	0D	3.76	37	25	4.24
14	0E	3.78	38	26	4.26
15	0F	3.80	39	27	4.28
16	10	3.82	40	28	4.30
17	11	3.84	41	29	4.32
18	12	3.86	42	2A	4.34
19	13	3.88	43	2B	4.36
20	14	3.90	44	2C	4.38
21	15	3.92	45	2D	4.40
22	16	3.94	46	2E	4.42
23	17	3.96	47 - 63	2F-3F	4.44

Note:

9. Default settings are denoted by **bold** typeface.

Provided DIS, CE# and HZ_MODE are LOW, a new charge cycle begins when one of the following occurs:

1. The battery voltage falls below V_{OREG} - V_{RCH} after charge termination has occurred.
2. Any I²C write occurs causing the T32 s timer to run.

Products that include the auto-charge feature also begin charging if:

3. VBUS Power-on-Reset (POR) occurs and the battery voltage is below the weak battery threshold (V_{LOWV}).

Charge Current Limit ($I_{OCHARGE}$)

Table 5. $I_{OCHARGE}$ Current as Function of $I_{OCHARGE}$ Bits (REG4 [6:3])

DEC	BIN	HEX	$I_{OCHARGE}$ (mA)
0	**0000**	**0**	**550**
1	0001	1	650
2	0010	2	750
3	0011	3	850
4	0100	4	950
5	0101	5	1,050
6	0110	6	1,150
7	0111	7	1,250
8	1000	8	1,350
9	1001	9	1,450
10-15	1010-1111	A-F	1,550

When the IO_LEVEL bit is set (default), the $I_{OCHARGE}$ bits are ignored and charge current is set to 340 mA.

PWM Controller in Charge Mode

The IC uses a current-mode PWM controller to regulate the output voltage and battery charge currents. The synchronous rectifier (Q2) has a negative current limit that turns off Q2 at 140 mA to prevent current flow from the battery.

Termination Current Limit

Current charge termination is enabled when TE (REG1[3])=1. Typical termination current values are given in Table 6.

Table 6. Termination Current as Function of ITERM Bits (REG4[2:0]) or PC_IT Bits (REG7[2:0]

ITERM Bits or PC_IT Bits	Termination Current (mA)
0	50
1	**100**
2	150
3	200
4	250
5	300
6	350
7	400

When the charge current falls below $I_{TERM;}$ PWM charging stops, but the STAT pin remains LOW. The STAT pin then goes HIGH and the STATUS bits change to CHARGE DONE (10), provided the battery and charger are still connected.

A post-charging feature, “top-off” charging, is available to continue the battery charging to a lower charge current to maximize battery capacity. The PC_EN bit must be set to 1 before the battery charging current reaches the termination current I_{TERM} for normal charging. The post-charging termination current is set by the PC_IT[2:0] bits, as shown in Table 6. If PC_EN is set to 1; right after the normal charging is ended as described above, post charging is started with PC_ON monitor bit set to 1. Once the current reaches the

threshold for post-charging completion, PWM charging stops and PC_ON bit changes back to 0.

During post-charging, the STAT pin is HIGH, indicating that the charge current is below the I_{TERM} level. To exit post-charging, one of the following must occur: a V_{BUS} POR, the POK_B cycled when V_{BAT} <3.0 V, or the CE# or HZ_Mode bit cycled.

Safety Timer

At the beginning of charging, the IC starts a 15-minute timer (t_{15MIN}). When this timer times out, charging is terminated. Writing to any register through I^2C stops and resets the t_{15MIN} timer, which in turn starts a 32-second timer (t_{32S}). Setting the TMR_RST bit (REG0[7]) resets the t_{32S} timer. If the t_{32S} timer times out; charging is terminated, the registers are set to their default values, and charging resumes using the default values with the t_{15MIN} timer running.

Normal charging is controlled by the host with the t_{32S} timer running to ensure that the host is alive. Charging with the t_{15MIN} timer running is used for charging unattended by the host. If the t_{15MIN} timer expires, the IC turns off the charger and indicates a timer fault (110) on the FAULT bits (REG0[2:0]). This sequence prevents overcharge if the host fails to reset the t_{32S} timer.

V_{BUS} POR / Non-Compliant Charger Rejection

256 ms after VBUS is connected, the IC pulses the STAT pin and sets the VBUS_CON bit. Before starting to supply current, the IC applies a 110 Ω load from VBUS to GND. V_{BUS} must remain above $V_{IN(MIN)1}$ and below $VBUS_{OVP}$ for t_{VBUS_VALID} (32 ms) before the IC initiates charging or supplies power to SYS. The V_{BUS} validation sequence always occurs before significant current is drawn from VBUS (for example, after a VBUS OVP fault or a V_{RCH} recharge initiation). t_{VBUS_VALID} ensures that unfiltered 50/60 Hz chargers and other non-compliant chargers are rejected.

USB-Friendly Boot Sequence

At V_{BUS} POR, when the battery voltage is above the weak battery threshold (V_{LOWV}); the IC operates in accordance with its I^2C register settings. If V_{BAT} < V_{LOWV} and t_{32s} is not running, the IC sets all registers to their default values and begins to deliver power to SYS.

FAN54040, FAN54042, and FAN54047 feature auto-charge, which allow these parts to deliver charge to the battery prior to receiving host commands.

FAN54041 does not automatically initiate charging at V_{BUS} POR. Instead, it waits in IDLE state for the host to initiate charging through I^2C commands. While in IDLE state, Q4 and Q5 are on. This allows the system to run through a separate power path without requiring an additional disconnection MOSFET.

Power Path Operation

As long as V_{BAT} < V_{BATMIN}, Q4 operates as a linear current source, (Power Path Mode) with its current limited to 340 mA. The IC then regulates SYS to 3.54 V and attempts to charge the battery with as much current as possible with the available I_{BUSLIM} input current, without allowing SYS to drop below 3.4 V. This ensures that system power always receives first priority from a limited input supply. During this time, POK_B is HIGH. If V_{BAT} < V_{SHORT}, Q4's current is further reduced to about 13 mA (I_{SHORT}) when I_{BUSLIM} is set to 100 or 500 mA. For all other input current limits, I_{SHORT} current is approximately 30 mA.

The POK_B signal can be used to keep the system in a low-power state, preventing excessive loading from the system while attempting to charge a depleted battery.

Table 7. VBATMIN Thresholds to Exit Power Path Mode

I_{BUSLIM} (mA)	V_{BATMIN} (V)
100	3.4
500	3.3
800	3.2
No Limit	3.2

After V_{BAT} reaches V_{BATMIN}, Q4 closes and is used as a current-sense element to limit I_{CHARGE} per the I^2C register settings by limiting the PWM modulator's current (Full PWM Mode). During PWM Mode, if SYS drops more than 5 mV (V_{THSYS}) below V_{BAT}, Q4 and Q5 are turned on (GATE is pulled LOW). Once SYS voltage becomes higher than V_{BAT}, Q5 is turned off and Q4 again serves as the current-sense element to limit $I_{OCHARGE}$.

Q4 and Q5 are both turned on when the IC enters SLEEP Mode (V_{BUS} < V_{BAT}).

POK_B pulls LOW once V_{BAT} reaches V_{LOWV}, and remains LOW as long as the IC is in Full PWM Mode. The IC remains in Full PWM Mode as long as V_{BAT} > 3.0 V, at which point, the IC enters Power Path Charging Mode.

Startup with a Dead Battery

At V_{BUS} POR, a 2 kΩ load is applied to VBAT for 256 ms to discharge any residual system capacitance in case the battery is absent or its discharge protection switch is open.

If V_{BAT} < V_{LOWV}, all registers are reset to default values and the IC charges in T15Min Mode. If V_{BAT} < V_{SHORT}, the SAFETY register is reset to its default value and the Battery Detection test below is performed.

Battery Detection

If V_{BAT} is below V_{SHORT} when charging is enabled, the DBAT_B bit is reset and the IC (except FAN54045 and FAN54046) performs an addition battery detection test.

After V_{BAT} rises above V_{SHORT}, PWM charging begins (when CE# = 0) with the float voltage (V_{OREG}) temporarily set to 4 V. If the battery voltage exceeds 3.7 V within 32 ms of the beginning of PWM charging, the battery is absent. If battery absence is detected:

1. STAT pulses, with FAULT bits set to 111, and the NOBAT bit is set.
2. For FAN54040 only; the t_{15MIN} timer is disabled until V_{BUS} is removed, IDLE state is entered, and POK_B remains HIGH.
3. The IC bypasses the protection switch close test below, since no battery is present.

The FAN54042 and FAN54047 continue to charge.

If V_{BAT} remained below 3.7 V during the initial 32 ms period, Power Path Mode charging continues to ensure that the

battery's discharge protection switch has closed before exiting Power Path Mode:

1. If V_{BAT} is less than 3.4 V, V_{SYS} is set to 4 V, and Power Path charging continues until V_{BAT} has exceeded 3.4 V for at least 128 ms. Charging continues until:
2. V_{BAT} has dropped below 3.2 V for at least 32 ms. Once this occurs, V_{SYS} returns to the OREG register setting (default 3.54 V).
3. V_{BAT} has again risen above V_{BATMIN} for at least 4 ms.

After these three events, PWM Mode is entered and the IC sets the DBAT_B bit. If the host sets the DBAT_B bit (Reg2[1]), events 1 and 2 above are skipped and PWM Mode is entered once V_{BAT} rises above V_{BATMIN}.

In a typical application, as soon as the host processor has cleared its UVLO threshold (typically 3.3 V), the host's low level software would set the IBUSLIM and IOCHARGE registers to charge the battery more rapidly above V_{BATMIN} as soon as the host determines that more than 100 mA is available through VBUS *(see Figure 37)*.

Once the host processor begins writing to the IC, charge parameters are set by the host, which must continually reset the t_{32S} timer to continue charging using the programmed charging parameters.

If t_{32S} times out; the register defaults are loaded, the FAULT bits are set to 110, STAT is pulsed, and charging continues with default charge parameters in T15MIN Mode for the FAN54040, FAN54042, and FAN54047.

POK_B (*see Table 8*)

The POK_B pin and bit are intended to provide feedback to the baseband processor that the battery is strong enough to allow the device to fully function. Whenever the IC is operating in Power Path Mode, POK_B is HIGH. On exiting Power Path Mode, POK_B remains HIGH until $V_{BAT} > V_{LOWV}$. Reg1[5:4] sets the V_{LOWV} threshold.

The STAT pin pulses any time the POK_B pin changes.

Table 8. Q4, Q5, POK_B, and GATE Operation vs. Charging Mode

Q4 CC-CV Control	V_{BUS}	V_{BAT}	V_{SYS}	Q4	Q5	GATE	POK_B
Power Path Mode: Maintain $V_{SYS} \geq 3.4$ V	Valid	$< V_{BATMIN}$	≤ 3.4	Linear	OFF	HIGH	HIGH
Power Path Mode: Limit $I_{CHARGE} \leq 340$ mA	Valid	$< V_{BATMIN}$	> 3.4	Linear	OFF	HIGH	HIGH
PWM Mode. Q4 Senses Current for I_{CHARGE}	Valid	$> V_{BATMIN}$ and $< V_{LOWV}$	X	ON	OFF	HIGH	HIGH
		$> V_{LOWV}$					LOW
OFF	$<V_{BAT}$	X	X	ON	ON	LOW	HIGH

Note:

10. POK_B remains LOW until Q4 returns to Power Path Mode. Q4 and Q5 are both ON if $V_{SYS} < V_{BAT}$ and CE# = 0. If CE# = 1 and $V_{SYS} < V_{BAT}$, Q5 is OFF and Q4 blocks current flow from VBAT to SYS.

Table 9. Q4, Q5 Operation as a Function of Relationship between V_{BUS} and V_{BAT}

PWM	Charger	CE#	V_{BUS}	V_{BAT}	Q4	Q5	GATE
ON	PWM Mode	0	Valid	$< V_{SYS}$, $>V_{BATMIN}$	ON	OFF	HIGH
ON	PWM Mode	0	Valid	$> V_{SYS}$, $>V_{BATMIN}$	ON	ON	LOW
ON	Disabled	1	Valid	X	OFF	OFF	HIGH
ON	Power Path Charging	0	Valid	$2\text{ V} < V_{BAT} < V_{BATMIN}$	Linear	OFF	HIGH
OFF	30 mA Linear Charging	X	Valid	$< 2\text{ V}_{BAT}$	ON	ON	LOW
OFF	OFF	X	X	X	ON	ON	LOW

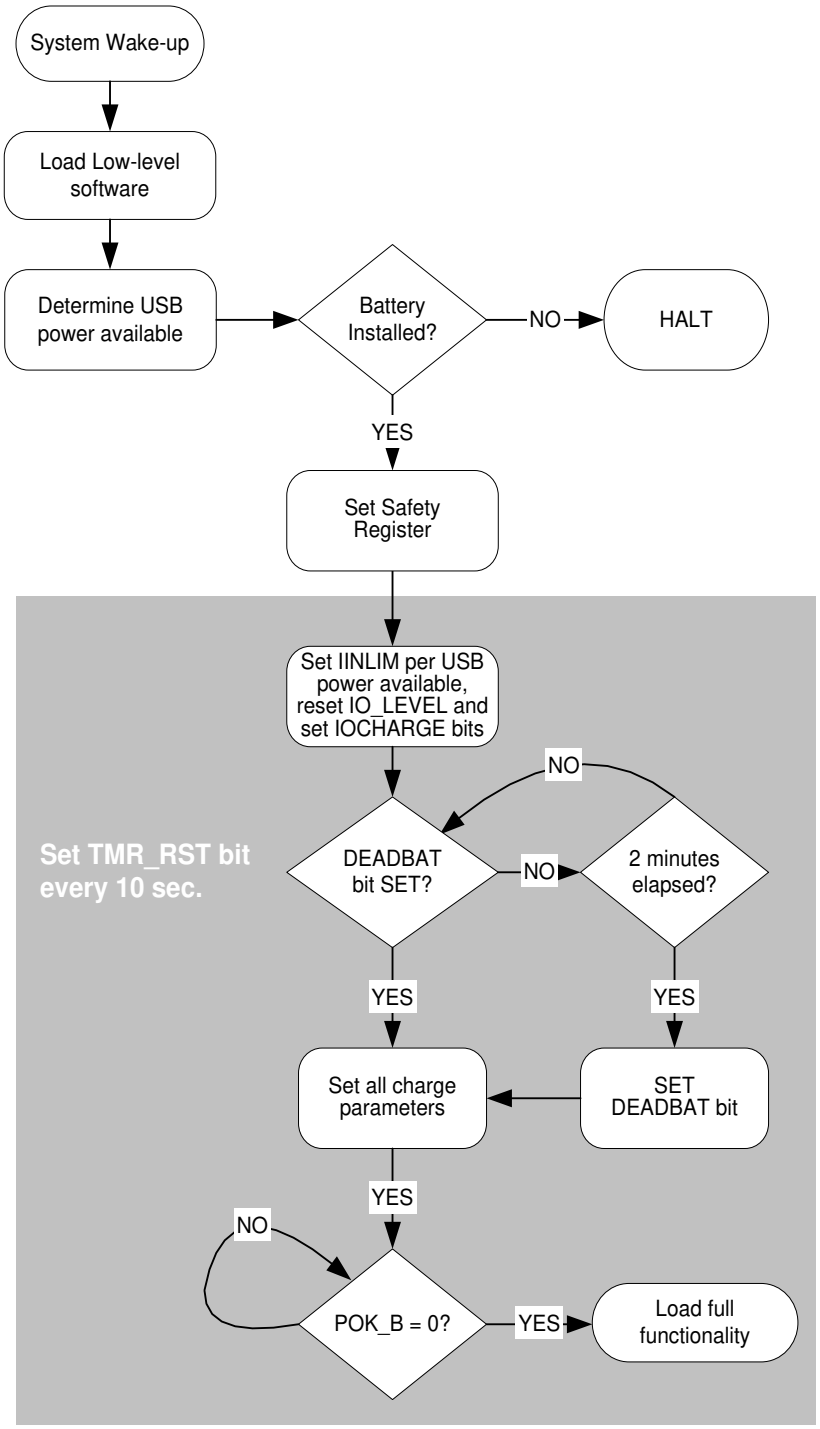


Figure 37. Recommended Host Software Sequence when Booting with Dead Battery

Battery Temperature (NTC) Monitor

The FAN5404X reduces the maximum charge current and termination voltage if an NTC measuring battery temperature (T_{BAT}) indicates that it is outside the fast-charging limits (T2 to T3), as described in the JEITA specification[1]. There are four temperature thresholds that change battery charger operation: T1, T2, T3, and T4, shown in Table 10.

Table 10. Battery Temperature Thresholds

For use with 10 kΩ NTC, β = 3380, and R_{REF} = 10 kΩ.

Threshold	Temperature	% of V_{REF}
T1	0°C	73.9
T2	10°C	64.6
T3	45°C	32.9
T4	60°C	23.3

Table 11. Charge Parameters vs. T_{BAT}

T_{BAT} (°C)	I_{CHARGE}	V_{FLOAT}
Below T1	Charging to VBAT Disabled	
Between T1 and T2	$I_{OCHARGE}$ / 2(11)	4.0 V
Between T2 and T3	$I_{OCHARGE}$	V_{OREG}
Between T3 and T4	$I_{OCHARGE}$ / 2(11)	4.0 V
Above T4	Charging to VBAT Disabled	

Note:

11. If $I_{OCHARGE}$ is programmed to less than 650 mA, the charge current is limited to 340 mA.

Thermistors with other β values can be used, with some shift in the corresponding temperature threshold, as shown in Table 12.

Table 12. Thermistor Temperature Thresholds

R_{REF} = R_{THRM} at 25°C

Parameter	Various Thermistors			
$R_{THRM(25°C)}$	10 kΩ	10 kΩ	47 kΩ	100 kΩ
β	3380	3940	4050	4250
T1	0°C	3°C	6	8
T2	10°C	12°C	13	14
T3	45°C	42°C	41	40
T4	60°C	55°C	53	51

The host processor can disable temperature-driven control of charging parameters by writing 1 to the TEMP_DIS bit. Since TEMP_DIS is reset whenever the IC resets its registers, the temperature controls are enforced whenever the IC is auto-charging, since auto-charge is always preceeded by a reset of registers.

To disable the thermistor circuit, tie the NTC pin to GND. Before enabling the charger, the IC tests to see if NTC is shorted to GND. If NTC is shorted to GND, no thermistor readings occur and the NTC_OK and NTC1-NTC4 is reset.

The IC first measures the NTC immediately prior to entering any PWM charging state, then measures the NTC once per second, updating the result in NTC1-NTC4 bits (Reg 12H[3:0]).

Table 13. NTC1-NTC4 Decoding

T_{BAT} (°C)	NTC4	NTC3	NTC2	NTC1
Above T4	1	1	1	1
Between T3 and T4	0	1	1	1
Between T2 and T3	0	0	1	1
Between T1 and T2	0	0	0	1
Below T1	0	0	0	0

[1] Japan Electronics and Information Technology Industries Association (JEITA) and Battery Association of Japan. "A Guide to the Safe Use of Secondary Lithium Ion Batteries in Notebook-type Personal Computers," April 28, 2007.

Flow Charts

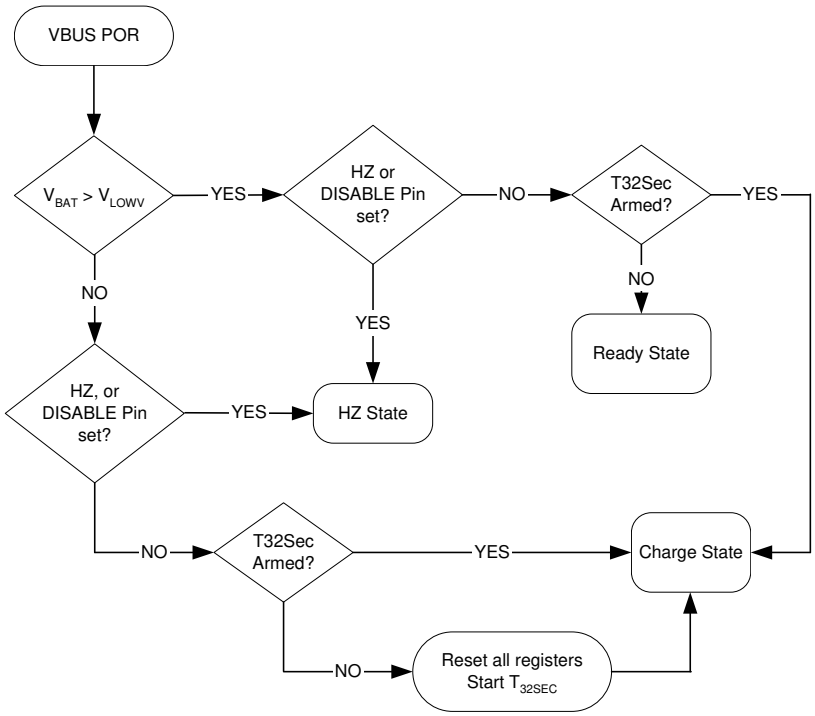


Figure 38. Charger V_{BUS} POR Flow Chart

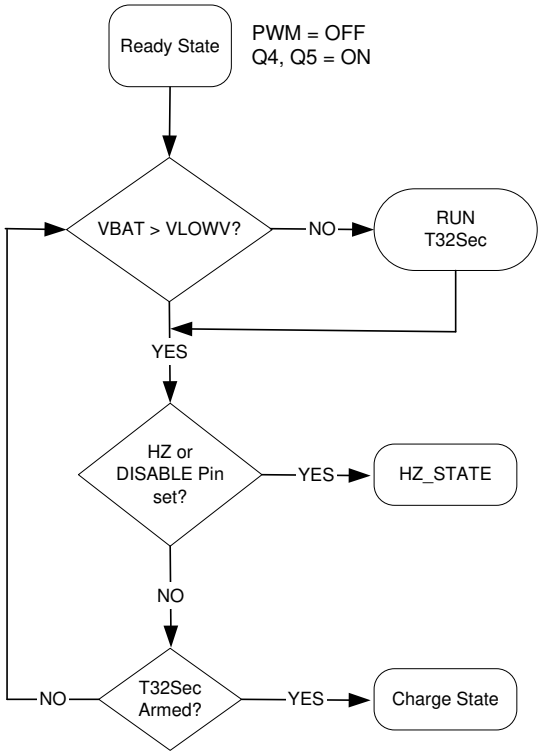


Figure 39. Ready State Flow Chart